

View Online at <https://aerobasegroup.com/nsn/5961-01-071-5344>

Inclosure Material:

Metal all transistor

Overall Length:

0.175 inches all transistor and 0.205 inches all transistor

Terminal Length:

0.500 inches all transistor

Overall Height:

0.170 inches all transistor and 0.210 inches all transistor

Overall Width:

0.125 inches all transistor and 0.165 inches all transistor

Internal Configuration:

Field effect all transistor

Channel Polarity And Control Type (non-core):

N-channel junction type all transistor

Component Function Relationship:

Matched

Component Name And Quantity:

2 transistor

Mounting Method:

Terminal all transistor

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all transistor

Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source all transistor and 6.0 gate to source cutoff voltage all transistor

Current Rating Per Characteristic:

15.00 milliamperes zero-gate-voltage source current megawatts all transistor

Power Rating Per Characteristic:

360.0 milliwatts small-signal input power, common-collector absolute all transistor

Terminal Type And Quantity:

3 uninsulated wire lead all transistor

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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